

#### General Description

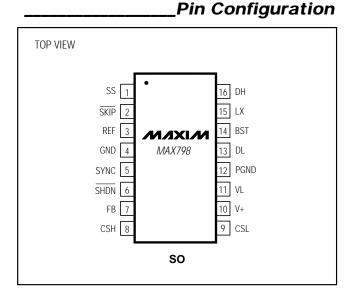
The MAX798 high-performance, step-down DC-DC converter provides main CPU power in battery-powered systems. This buck controller achieves 96% efficiency by using synchronous rectification and Maxim's proprietary Idle Mode™ control scheme to extend battery life at full-load (up to 10A) and no-load outputs. The MAX798's high accuracy meets the demanding requirements of the latest-generation CPUs. Excellent dynamic response corrects output transients caused by the latest dynamic-clock CPUs within five 300kHz clock cycles. Unique bootstrap circuitry drives inexpensive N-channel MOSFETs, reducing system cost and eliminating the crowbar switching currents found in some PMOS/NMOS switch designs.

The MAX798 has a logic-controlled and synchronizable fixed-frequency pulse-width-modulating (PWM) operating mode, which reduces noise and RF interference in sensitive mobile-communications and pen-entry applications. The SKIP override input allows automatic switchover to idle-mode operation (for high-efficiency pulse skipping) at light loads, or forces fixed-frequency mode for lowest noise at all loads.

### \_Applications

Notebook and Subnotebook Computers

PDAs and Mobile Communicators



Idle Mode is a trademark of Maxim Integrated Products.

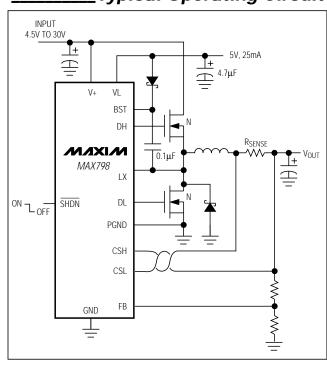
#### **Features**

- ♦ 96% Efficiency
- ♦ 4.5V to 30V Input Range
- **♦ 1.6V to 6V Adjustable Precision Output**
- ♦ ±0.4% Max Total Load-Regulation Error
- ♦ 0.06%/V Max Line-Regulation Error
- ♦ 5V Linear-Regulator Output
- ♦ Precision 2.505V Reference Output
- **♦** Automatic Bootstrap Circuit
- ◆ 150kHz/300kHz Fixed-Frequency PWM Operation
- ♦ Programmable Soft-Start
- ♦ 1.2mA Typical Quiescent Current (VIN = 12V, VOUT = 2.5V)
- ♦ 1µA Typical Shutdown Current

### \_Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX798ESE	-40°C to +85°C	16 Narrow SO

### Typical Operating Circuit



#### **ABSOLUTE MAXIMUM RATINGS**

V+ to GND	0.3V. +36V
GND to PGND	,
VL to GND	0.3V, +7V
BST to GND	
DH to LX	0.3V, (BST + 0.3V)
LX to BST	7V, +0.3Ý
SHDN to GND	
SYNC, SS, REF, SKIP, DL to GND	0.3V, (VL + 0.3V)
CSH, CSL to GND	0.3V, +7V
VL Short Circuit to GND	Momentary

REF Short Circuit to GND	Continuous
VL Output Current	50mA
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
SO (derate 8.70mW/°C above +70°C)	696mW
Operating Temperature Range	
MAX798ESE	40°C to +85°C
Storage Temperature Range	65°C to +160°C
Lead Temperature (soldering, 10sec)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

(V+ = +15V, GND = PGND = 0V,  $I_{VL}$  =  $I_{REF}$  = 0A,  $I_{A}$  = 0°C to +85°C, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
STEP-DOWN CONTROLLER					
Input Supply Range		4.5		30	V
Nominal Adjustable Output Voltage Range	External resistor divider	1.6		6	V
Feedback Voltage	CSH - CSL = 40mV, SKIP = VL	1.576	1.6	1.624	V
Load Regulation	0mV < (CSH - CSL) < 80mV, SKIP = VL			±0.4	%
Line Regulation	6V < V+ < 30V		0.04	0.05	%/V
Command Limit Valtage	CSH - CSL, positive	80	100	120	2001/
Current-Limit Voltage	CSH - CSL, negative	-40	-100	-160	mV
SS Source Current		2.0	4.0	6.5	μΑ
SS Fault Sink Current		2.0			mA
INTERNAL REGULATOR AND F	REFERENCE				-
VL Output Voltage	SHDN = 2V, 0mA < I <sub>VL</sub> < 25mA, 5.5V < V+ < 30V	4.75		5.25	V
VL Fault Lockout Voltage	Rising edge, hysteresis = 15mV	3.8		4.0	V
VL/CSL Switchover Voltage	Rising edge, hysteresis = 25mV	4.2		4.7	V
Reference Output Voltage	No external load (Note 1)	2.463	2.505	2.537	V
Reference Fault Lockout Voltage	Falling edge	1.8		2.3	V
Reference Load Regulation	0μA < I <sub>REF</sub> < 100μA			20	mV
CSL Shutdown Leakage Current	SHDN = 0V, CSL = 6V, V+ = 0V or 30V, VL = 0V		0.1	1	μΑ
V+ Shutdown Current	SHDN = 0V, V+ = 30V, CSL = 0V or 6V		1	5	μA
V+ Off-State Leakage Current	FB = CSH = CSL = 6V, VL switched over to CSL		1	5	μΑ
Dropout Power Consumption	V+ = 4V, CSL = 0V (Note 2)		6.6	10.5	mW
Quiescent Power Consumption	CSH = CSL = 6V		6.4	8.5	mW

### **ELECTRICAL CHARACTERISTICS (continued)**

(V+ = +15V, GND = PGND = 0V,  $I_{VL}$  =  $I_{REF}$  = 0A,  $I_{A}$  = 0°C to +85°C, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
Oscillator Frequency	SYNC = REF	270	300	330	kHz	
Oscillator Frequency	SYNC = 0V or 5V	125	150	175		
SYNC High Pulse Width		200			ns	
SYNC Low Pulse Width		200			ns	
SYNC Rise/Fall Time	Guaranteed by design			200	ns	
Oscillator Sync Range		195		340	kHz	
Maximum Duty Cyala	SYNC = REF	89	91		- %	
Maximum Duty Cycle	SYNC = 0V or 5V	93	96		70	
Input High Voltage	SYNC	VL - 0.5			V	
Input High Voltage	SHDN, SKIP	2.0				
Input Low Voltage	SYNC			0.8	V	
Input Low Voltage	SHDN, SKIP			0.5		
	SHDN, 0V or 30V			2	μΑ	
Input Current	SYNC, SKIP			1		
Input Current	CSH, CSL, CSH = CSL = 4V, device not shut down			50	1	
	FB, FB = 1.6V			±100	nA	
DL Sink/Source Current	DL forced to 2V		1		А	
DH Sink/Source Current	DH forced to 2V, BST - LX = 4.5V		1		А	
DL On-Resistance	High or low			7	Ω	
DH On-Resistance	High or low, BST - LX = 4.5V			7	Ω	

#### **ELECTRICAL CHARACTERISTICS**

 $(V+ = +15V, GND = PGND = 0V, I_{VL} = I_{REF} = 0A, T_A = -40^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted.) (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
STEP-DOWN CONTROLLER		<u> </u>				
Input Supply Range		5.0		30	V	
Nominal Adjustable Output Voltage Range	External resistor divider	1.6		6.0	V	
Feedback Voltage	CSH - CSL = 40mV, SKIP = VL	1.560	1.6	1.640	V	
Load Regulation	0mV < (CSH - CSL) < 80mV, SKIP = VL			±1	%	
Line Regulation	6V < V+ < 30V		0.04	0.06	%/ V	
Current-Limit Voltage	CSH - CSL, positive	70		130	mV	
Current-Limit voltage	CSH - CSL, negative	-40	-100	-160	7 1117	
INTERNAL REGULATOR AND	REFERENCE					
VL Output Voltage	SHDN = 2V, 0mA < I <sub>VL</sub> < 25mA, 5.5V < V+ < 30V	4.7		5.3	V	
VL Fault Lockout Voltage	Rising edge, hysteresis = 15mV	3.75		4.05	V	
VL/CSL Switchover Voltage	Rising edge, hysteresis = 25mV	4.15		4.75	V	
Reference Output Voltage	No external load (Note 1)	2.438	2.505	2.562	V	
Reference Load Regulation	0μA < I <sub>REF</sub> < 100μA			30	mV	
V+ Shutdown Current	SHDN = 0V, V+ = 30V, CSL = 0V or 6V		1	10	μΑ	
V+ Off-State Leakage Current	FB = CSH = CSL = 6V, VL switched over to CSL		1	10	μΑ	
Quiescent Power Consumption	CSH = CSL = 6V		6.4	9.1	mW	
OSCILLATOR AND INPUTS/OU	JTPUTS					
Oscillator Fraguescy	SYNC = REF	250	300	350	kHz	
Oscillator Frequency	SYNC = 0V or 5V	110	150	190		
SYNC High Pulse Width		250			ns	
SYNC Low Pulse Width		250			ns	
Oscillator Sync Range		210		320	kHz	
Maximum Duty Cycle	SYNC = REF	88	91		%	
waxiindin Duty Cycle	SYNC = 0V or 5V	92	96		/0	
DL On-Resistance	High or low			7	Ω	
DH On-Resistance	High or low, BST - LX = 4.5V			7	Ω	

- Note 1: Since the reference uses VL as its supply, V+ line-regulation error is insignificant.
- Note 2: At very low input voltages, quiescent supply current can increase due to excess PNP base current in the VL linear regulator. This occurs only if V+ falls below the preset VL regulation point (5V nominal). The typical maximum quiescent current in dropout will not exceed 16mA.
- **Note 3:** All -40°C to +85°C specifications above are guaranteed by design.

### Pin Description

PIN	NAME	FUNCTION
1	SS	Soft-Start Timing Capacitor Connection. Ramp time to full current limit is approximately 1ms/nF.
2	SKIP	Disables pulse-skipping mode when high. Connect to GND for normal use. <b>Don't leave SKIP unconnected.</b> With SKIP grounded, the device will <i>automatically</i> change from pulse-skipping operation to full PWM operation when the load current exceeds approximately 30% of maximum.
3	REF	Reference Voltage Output. Bypass to GND with 0.33µF minimum.
4	GND	Low-Noise Analog Ground and Feedback Reference Point
5	SYNC	Oscillator Synchronization and Frequency Select. Tie to GND or VL for 150kHz operation; tie to REF for 300kHz operation. A high-to-low transition begins a new cycle. Drive SYNC with 0V to 5V logic levels (see the <i>Electrical Characteristics</i> table for V <sub>IH</sub> and V <sub>IL</sub> specifications). SYNC capture range is 195kHz to 340kHz.
6	SHDN	Shutdown Control Input, active low. Logic threshold is set at approximately 1V (V <sub>TH</sub> of an internal N-channel MOSFET). Tie SHDN to V+ for automatic start-up.
7	FB	Feedback Input. Regulates at FB = 1.6V. Connect FB to a resistor divider to set the output voltage.
8	CSH	Current-Sense Input, high side. Current-limit level is 100mV referred to CSL.
9	CSL	Current-Sense Input, low side
10	V+	Battery Voltage Input (4.5V to 30V). Bypass V+ to PGND close to the IC with a 0.1µF capacitor. Connects to a linear regulator that powers VL.
11	VL	5V Internal Linear-Regulator Output. VL is also the supply voltage rail for the chip. VL is switched to the output voltage via CSL (V <sub>CSL</sub> > 4.5V) for automatic bootstrapping. Bypass to GND with 4.7μF. VL can supply up to 5mA for external loads.
12	PGND	Power Ground
13	DL	Low-Side Gate-Drive Output. Normally drives the synchronous-rectifier MOSFET. Swings 0V to VL.
14	BST	Boost Capacitor Connection for high-side gate drive (0.1µF)
15	LX	Switching Node (inductor) Connection. Can swing 2V below ground without hazard.
16	DH	High-Side Gate-Drive Output. Normally drives the main buck switch. DH is a floating driver output that swings from LX to BST, riding on the LX switching-node voltage.

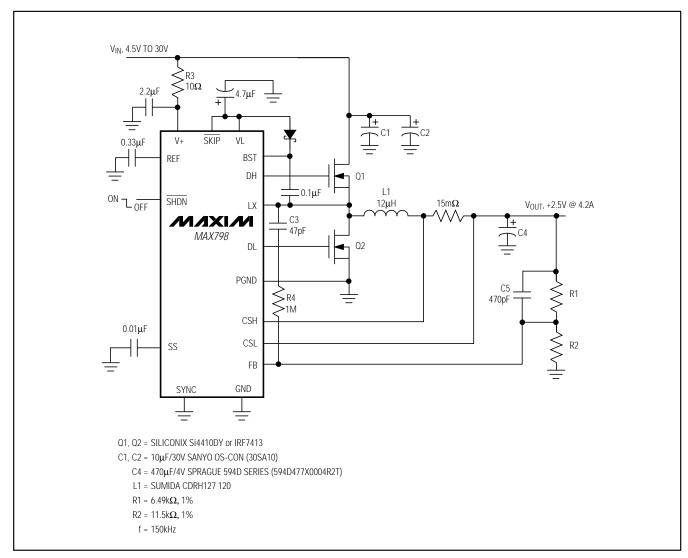


Figure 1. Standard Application Circuit

### Detailed Description

The MAX798 is a BiCMOS, switch-mode power-supply controller designed primarily for buck-topology regulators in battery-powered applications where high accuracy, high efficiency, and low quiescent supply current are critical. The MAX798 also works well in other topologies such as boost, inverting, and CUK due to the flexibility of its floating high-speed gate driver. Light-load efficiency is enhanced by automatic idlemode operation—a variable-frequency pulse-skipping

mode that reduces losses due to MOSFET gate charge. The step-down power-switching circuit consists of two N-channel MOSFETs, a rectifier, and an LC output filter. The output voltage is the average of the AC voltage at the switching node, which is adjusted and regulated by changing the duty cycle of the MOSFET switches. The gate-drive signal to the N-channel high-side MOSFET must exceed the battery voltage and is provided by a flying capacitor boost circuit that uses a 100nF capacitor connected between BST and LX.

The MAX798 contains the following seven major circuit blocks, which are shown in Figure 2.

PWM Controller Blocks:

- Multi-Input PWM Comparator
- Current-Sense Circuit
- PWM Logic Block
- Gate-Driver Outputs

Bias Generator Blocks:

- +5V Linear Regulator
- Automatic Bootstrap Switchover Circuit
- +2.505V Reference

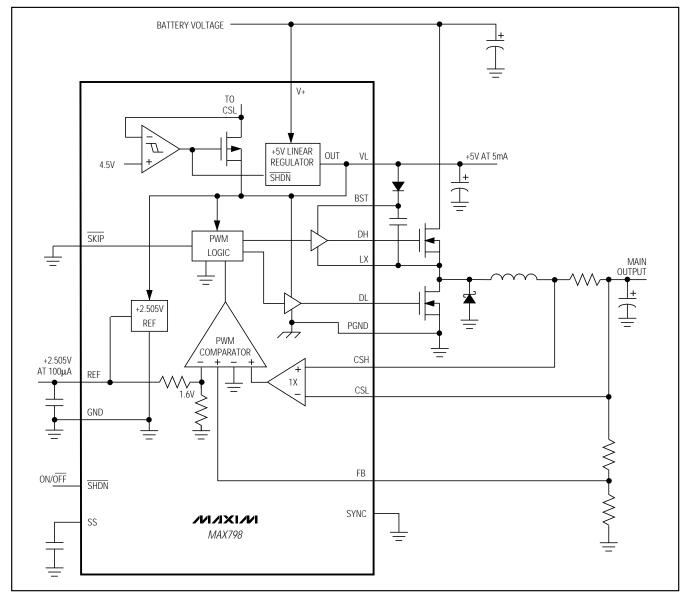


Figure 2. Functional Diagram

These internal IC blocks aren't powered directly from the battery. Instead, a +5V linear regulator steps down the battery voltage to supply both the IC internal rail (VL pin) as well as the gate drivers. The synchronous-switch gate driver is directly powered from +5V VL, while the high-side-switch gate driver is indirectly powered from VL via an external diode-capacitor boost circuit. An automatic bootstrap circuit turns off the +5V linear regulator and powers the IC from its output voltage if the output is above 4.5V.

#### **PWM Controller Block**

The heart of the current-mode PWM controller is a multi-input open-loop comparator that sums three signals: output voltage error signal with respect to the reference voltage, current-sense signal, and slope compensation ramp (Figure 3). The PWM controller is a direct summing type, lacking a traditional error amplifier and the phase shift associated with it. This direct-summing configuration approaches the ideal of cycle-by-cycle control over the output voltage.

For more comprehensive information on the MAX798 internal blocks, please refer to the MAX796/MAX797/MAX799 data sheet.

### Applications Information

#### Powering VL from a +5V Supply

If the circuit's output voltage is greater than the VL/CSL switchover voltage, the IC automatically bootstraps and runs off its output. Running from the high-efficiency output rather than the VL linear regulator is particularly desirable if the input voltage is high. If the output is not greater than the VL/CSL switchover threshold, efficiency can be improved by powering VL from another efficient system supply (Figure 4).

VL can be connected directly to a +5V supply, provided its maximum excursions are within a 4.5V to 6V range and the main output voltage's maximum is less than 4.2V. If the circuit's output voltage is greater than 4.2V, the IC can activate its internal bootstrap switch and connect the circuit output to VL.

#### Adjusting the Output Voltage

The output voltage is set by an external resistor divider between the output voltage and GND, with the midpoint connected to FB (Figure 5). The output voltage can be adjusted from 1.6V to 6V, according to the formula in Figure 5. Recommended R2 values range from 5k  $\,\Omega$  to 100k $\,\Omega$ . For best noise immunity, place R1 and R2 close to FB. For a 1.6V output, connect the output voltage directly to FB.

Remote sensing of the output voltage is easily achieved by connecting the top of R1 and, if desired, the bottom of R2, to the remote sense point.

### Bypassing and Compensation Components

The MAX798 is designed to deliver a more accurate output voltage than the MAX797. A major source of the MAX797's output error is the decrease in output voltage with increasing load. This error is greatly reduced in the MAX798 by increasing the gain of the voltage-sense signal relative to the current-sense signal. As a result of this increased gain, the MAX798 is slightly more noise sensitive than the MAX797, and requires some small compensation components as well. On the other hand, output capacitor ESR requirements can be greatly relaxed compared to the MAX797, with the limiting factor being the maximum total output voltage ripple that the application can tolerate.

To control noise problems, place the bypass capacitors on REF, VL, and V+ as close as possible to the IC, and use a  $10\Omega$  series resistor (R3, Figure 1) on V+ to form a small lowpass filter. Feed-forward components (R4, C3, and C5) are chosen for stable switching at 150kHz with the components shown. For 300kHz switching and a 4.7µH inductor, use R4 = 470k  $\Omega$  and C5 = 220pF. Keep the components that connect to FB (R4, C5, R1, R2) close to the IC's FB pin.

#### **Design Procedure**

With the exception of the items previously mentioned, follow the design procedure for the MAX797. The MAX796/MAX797/MAX799 data sheet contains all necessary information on component values, component selection, layout, and additional applications.

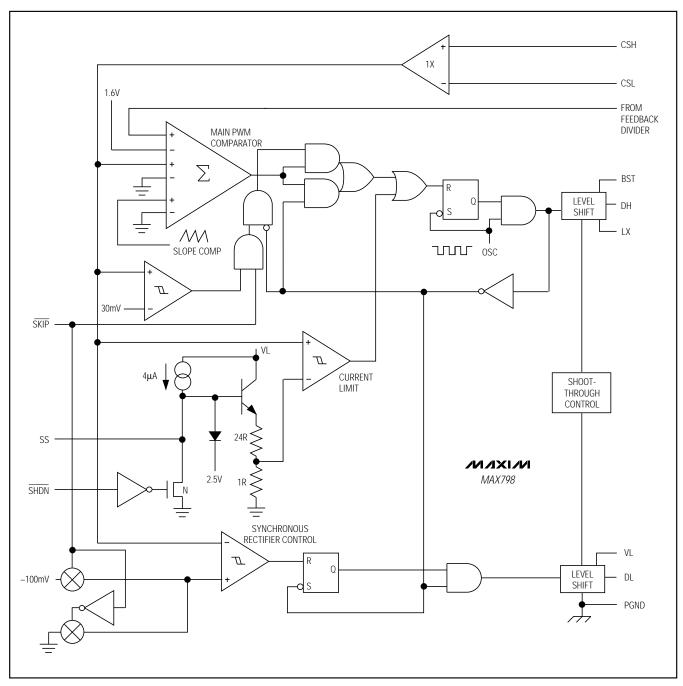


Figure 3. PWM Controller Detailed Block Diagram

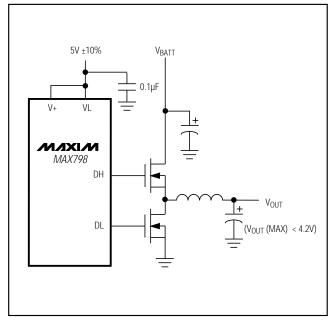


Figure 4. Powering VL from a Separate +5V Supply

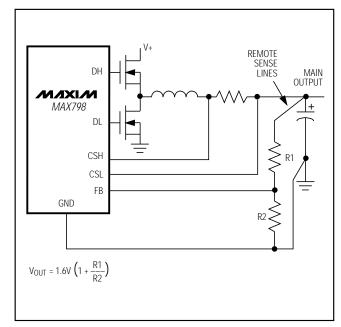


Figure 5. Adjusting the Output Voltage

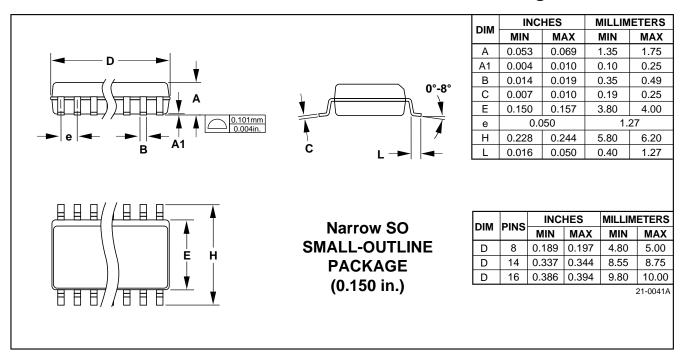
# **MAX798**

# High-Accuracy Step-Down Controller with Synchronous Rectifier for CPU Power

Chip Information

TRANSISTOR COUNT: 1008

### Package Information



**NOTES** 

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